AC6363F Datasheet

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Version: V1.1

Date: 2022.07.19

AC6363F Features

CPU

- 32-bit DSP supports hardware Float Point Unit (FPU)
- Up to 160MHz programmable processor
- 64Vectored interrupts
- 4 Levels interrupt priority

Bluetooth

- Compliant with BluetoothV5.3+BR+EDR+BLE specification
- Meet class1 class2 and class3 transmitting power requirement
- Support GFSK and $\pi/4$ DQPSK all paket types
- Provides +6dbm transmitting power
- receiver with -90dBm sensitivity
- Fast AGC for enhanced dynamic range
- Supports a2dp\avctp\avdtp\avrcp\hfp\spp\smp\att\gap\ gatt\rfcomm\sdp\l2cap profile

Temperature

- Operating temperature: -40°C to +85°C
- Storage temperature: -65°C to +150°C

Peripherals

- One full speed USB 2.0 OTG controller
- Six multi-function 32-bit timers, support capture and PWM mode
- Three full-duplex basic UART, UART0 and UART1 supports DMA mode
- Two SPI interface supports host and device mode
- One hardware IIC interface supports host and device mode
- 10-bit ADC for analog sampling
- External wake up/interrupt on all GPIOs

PMU

- Low voltage LDO for internal digital and analog circuit supply
- 3uA current consumption in the soft-off mode
- Built-in LDO for the core, I/O, Bluetooth and flash
- **VBAT** is 2.0V to 4.5V
- VDDIO is 2.0V to 3.4V

Packages

QFN20(3mm*3mm)

Applications

Bluetooth IOT

1. Pin Definition

1.1 Pin Assignment

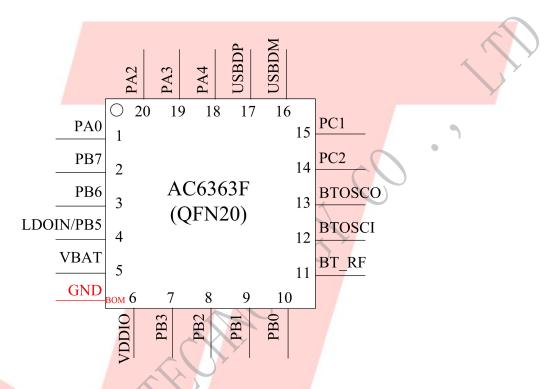


Figure 1-1 AC6363F Package Diagram

1.2 Pin Description

Table 1-1 AC6363F Pin Description

PIN NO.	Name	I/O Type	Drive (mA)	Function	Other Function
1	PA0	I/O		GPIO	ADC0: ADC Input Channel 0; UART1TXC: Uart1 Data Output(C);
2	PB7	I/O		GPIO	IIC_SDA_C: IIC DAT(C); SPI2_DOA: SPI2 Data Out(A); ADC9: ADC Input Channel 9; PWM5: Timer5 PWM Output; UART1RXA: Uart1 Data In(A);
3	PB6	I/O		GPIO	IIC_SCL_C: IIC SCL(C); SPI2_CLKA: SPI2 Clock(A); ADC8: ADC Input Channel 8; TMR3: Timer3 Clock Input; UART1TXA: Uart1 Data Out(A);
4	PB5	I/O		GPIO (High Voltage Resistance)	PWM3: Timer3 PWM Output; SPI2_DIA: SPI2 Data In(A); CAP1: Timer1 Capture; UART0TXC: Uart0 Data Out(C); UART0RXC: Uart0 Data In(C); Battery Charger In
5	VBAT	P) /		Battery Power Supply
6	VDDIO	P	1		IO Power 3.3v
7	PB3	I/O		GPIO	ADC6: ADC Input Channel 6; PWM2: Timer2 PWM Output; UART2RXB: Uart2 Data In(B);
8	PB2	I/O		GPIO (High Voltage Resistance)	SPI1DIA: SPI1 Data In(A); CAP0: Timer0 Capture; UART2TXB: Uart2 Data Out (B);
9	PB1	I/O		GPIO (pull up)	Long Press Reset; SPI1DOA: SPI1 Data Out(A); ADC5: ADC Input Channel 5; TMR2: Timer2 Clock Input; UART0RXB: Uart0 Data In(B);

					T
				GPIO	SPI1CLKA: SPI1 Clock(A);
10	PB0	I/O		(High Voltage	UART0TXB: Uart1 Data Out(B);
				Resistance)	TMR5: Timer5 Clock Input;
11	BT_RF	/			BT Antenna
12	BTOSCI	I			BT OSC In
13	BTOSCO	0			BT OSC Out
14	PC2	I/O		GPIO	ADC10: ADC Input Channel 10; CAP5: Timer5 Capture; UART1RXB: Uart1 Data In(B);
15	PC1	I/O		GPIO	TMR0: Timer0 Clock Input;
16	USBDM	I/O		USB Negative Data (pull down)	IIC_SDA_A: IIC SDA(A); SPI2_DOB: SPI2 Data Out(B); ADC14: ADC Input Channel 14; UART1RXD: Uart1 Data In(D);
17	USBDP	I/O		USB Positive Data (pull down)	IIC_SCL_A: IIC SCL(A); SPI2_CLKB: SPI2 Clock(B); ADC13: ADC Input Channel 13; UART1TXD: Uart1 Data Output(D);
18	PA4	I/O		GPIO	UART1_RTS: Uart1 Request to send; ADC3: ADC Input Channel 3; TMR4: Timer4 Clock Input; UART2RXA: Uart2 Data In(A);
19	PA3	I/O		GPIO	UART1_CTS: Uart1 Clear to send; ADC2: ADC Input Channel 3; PWM5: Timer5 PWM Output; UART2TXA: Uart1 Data Output(D);
20	PA2	I/O)	GPIO	CAP3: Timer3 Capture;
	Substrate	GND	- /	Substrate	P

2, Electrical Characteristics

2.1 Absolute Maximum Ratings

Table 2-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	4.5	V
LDOIN	Charger Voltage	-0.3	6	V
V _{3.3IO}	3.3V IO Input Voltage	-0.3	3.6	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

2.2 Recommended Operating Conditions

Table 2-2

Symbol	Parameter	Min	Тур	Max	Unit		Test Conditions
VBAT	Voltage Input	2.0	3.7	4.5	V		
LDOIN	Charger Voltage	4.5	5	5.5	V		
V_{VDDIO}	Voltage output	2.0	3.0	3.4	V		VBAT = 4.2V, 100mA loading
I _{L3.3}	Loading current	_		150	mA	y	VBAT = 4.2V

2.3 Battery Charge

Table 2-3

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
LDO_IN	Charge Input Voltage	4.5	5	5.5	V	-
$V_{ m Charge}$	Charge Voltage	4.15	4.2	4.25	V	-
I_{Charge}	Charge Current	20		200	mA	Charge current at fast charge mode
I_{Trikl}	Trickle Charge Current	20	45	70	mA	$V_{BAT} \!\!<\!\! V_{Trikl}$

2.4 IO Input/Output Electrical Logical Characteristics

Table 2-4

IO input ch	aracteristics					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
V_{IL}	Low-Level Input Voltage	-0.3	-	0.3* VDDIO	V	VDDIO = 3.3V
$ m V_{IH}$	High-Level Input Voltage	0.7* VDDIO	-	VDDIO+0.3	V	VDDIO = 3.3V
IO output o	characteristics					7
V _{OL}	Low-Level Output Voltage	-	-	0.33	V	VDDIO = 3.3V
V_{OH}	High-Level Output Voltage	2.7	-	7.4	V	VDDIO = 3.3V

2.5 Internal Resistor Characteristics

Table 2-5

	Port	General Output	High Drive	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
PE PB	2~PA4 81,PB3 6~PB7 1~PC2	8mA	24mA	10K	10K	
PA0	Output 0 Output 1	8mA	24mA 64mA	10K	10K	1. USBDM & USBDP default pull down 2. PB0,PB2,PB5 can pull-up resistance to 5V 3. internal pull-up/pull-down resistance accuracy ±20%
PB0,	PB2,PB5	8mA	_	10K	10K	
U	SBDP	4mA	_	1.5K	15K	
US	SBDM	4mA	-	180K	15K	

2.6 BT Characteristics

2.6.1 Transmitter

Basic Data Rate

Table 2-6

Busic Butu Itute			rubie 2			
Paramete	r	Min	Тур	Max	Unit	Test Conditions
RF Transmit P	ower		4	6	dBm	\
RF Power Contro	l Range		20		dB	25°C,
20dB Bandw	idth		950		KHz	Power Supply
	+2MHz		-40		dBm	
Adjacent Channel	-2MHz		-38	7/	dBm	VBAT=5V
Transmit Power	+3MHz		-44	/ /	dBm	2441MHz
	-3MHz	A	-35		dBm	l).

Enhanced Data Rate

Table 2-7

Paramete	Parameter			Max	Unit	Test Conditions
Relative Po	wer		<u>_</u> -1		dB	
π/4 DQPSK	DEVM RMS	, 4	6)	%	
·	DEVM 99%	0	10		%	25°C,
Modulation Accuracy	DEVM Peak	5	15	y	%	Power Supply
	+2MHz		-40	Ţ.	dBm	VBAT=5V
Adjacent Channel	-2MHz		-38	N. I.	dBm	2441MHz
Transmit Power	+3MHz		-44		dBm	
	-3MHz	1.1	-35		dBm	

2.6.2 Receiver

Basic Data Rate

Table 2-8

Paramete	er	Min	Тур	Max	Unit	Test Conditions
Sensitivit	y		-90		dBm	
Co-channel Interferer	nce Rejection		-13		dB	
\mathcal{O}	+1MHz		+5		dB	25°C,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37		dB	VBAT=5V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz		+40		dB	
	-3MHz		+35		dB	

Enhanced Data Rate

Table 2-9

Paramete	Parameter			Max	Unit	Test Conditions
Sensitivit	y		-90		dBm	
Co-channel Interferer	nce Rejection		-13		dB	
	+1MHz		+5		dB	25°C,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37		dB	VBAT=5V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz		+40		dB	
	-3MHz		+35		dB	

3. Package Information

3.1 QFN20

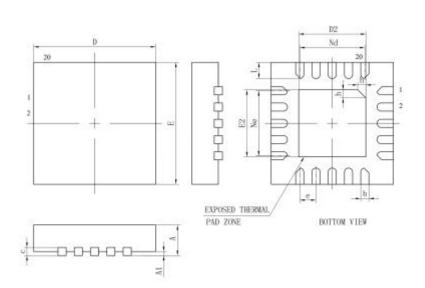




Figure 3-1 AC6363F Package

4. Revision History

Date	Revision	Description
2020.07.13	V1.0	Initial Release
2022.07.19	V1.1	Update Bluetooth Feature